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	C	Complete if Known
_	Application Number	1/1/7/1,023
Ξ	Filing Date	3 February 2004 (herewith)
Γ	First Named Inventor	Hsiang Lan, Lung
	Group Art Unit	2829
	Examiner Name	

Substitute for form 1449A/PTO INFORMATION DISCLOSUR STATEMENT BY APPLICAN (use as many sheets as necessary) Sheet Attorney Docket Number | MXIC 1564-1

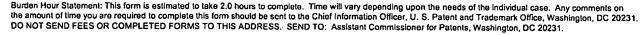
				U.S. PATENT DOCL	JMENTS	
Examiner Inilials*	Cite No.1	U.S. Patent Docum Kind Number (if kn	Code ²	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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			FORE	IGN PATENT DOCUMEN	TS		
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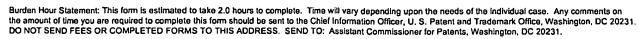
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STA	TEMENT	RY A	APPLICANT	First Named Inventor	Hsiang Lan Lung
UIA		U .,	(Group Art Unit	2824
	(use as man)	y sheets a	s necessary)	Examiner Name	
Sheet	2	of	2	Attorney Docket Number	MXIC 1564-1

		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T2
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Examiner Signature	/Eric J. Wendler/	Date Considered	02/05/2007
Signature		Considered	J

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Complete if Known Substitute for form 1449/PTO Application Number 10/771,023 Filing Date 3 February 2004 INFORMATION DISCLOSURE First Named Inventor HSIANG LAN LUNG STATEMENT BY APPLICANT Art Unit Not assigned (Use as many sheets as necessary) Examiner Name Not assigned Attorney Docket Number MXIC 1564-1

Examiner	Cite	Document Number	Publication Date	DOCUMENTS	1 6
Initials*	Cite No.	Number-Kind Code ^{2 (F known)}	MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Unes, Where Relevant Possoges or Relevan Figures Appear
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		FORE	IGN PATENT DOCU	MENTS		
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		OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS	
Examiner Initists*	Cibs No.1	Include name of the author (in CAPITAL LETTERS), title of the stricle (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), data, page(s), volume-issue number(s), publisher, city and/or country where published,	1,3
EJW	C1	LANCASTER et al., "A 5V-Only EEPROM with Internal Program/Erase Control," ISSCC 83/ Thursday, February 24, 1983/Imperial Ballroom B/2:00 p.m., IEEE International Solid State Circuits Conference, 3 pages	
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Examiner Signature	/Eric J. Wendler/	Date Considered	02/05/2007

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